

RTX5032A

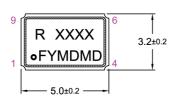
Specifications

1.0	SPECIFICATION REFERE	ENCES		
Line	Parameter	Description		
1.1	Model description	RTX5032A 12.800 MHz		
1.2	RoHS compliant	Yes		
1.3	Filter	Enabled		
1.4	Reference number	RTX5032A-56		
1.5	Rakon part number	509237		
1.6	Current Version	1.01		
2.0	FREQUENCY CHARACTE	RISTICS		
Line	Parameter	Test Condition	Value	Unit
2.1	Frequency	Nominal frequency	12.800	MHz
2.2	Frequency calibration	Offset from nominal frequency measured at 25°C ± 2°C	±1 max	ppm
2.3	Reflow shift	Two consecutive reflows as per attached profile after 1 hour recovery at 25°C	±1 max	ppm
2.4	Frequency stability over temperature	Referenced to the midpoint between minimum and maximum frequency value over the specified temperature range (Note 1, 2)	±0.28 max	ppm
2.5	Temperature range	The operating temperature range over which the frequency stability is measured	-40 to 85	°C
2.6	Frequency slope	Minimum of 1 frequency reading every 2° C, over the operating temperature range (Note 1, 2)	0.1 max	ppm/°C
2.7	Static temperature hysteresis	Frequency change after reciprocal temperature ramped over the operating range. Frequency measured before and after at 25°C	0.4 max	ppm
2.8	Supply voltage stability	Supply voltage varied ±5% at 25°C	±0.1 max	ppm
2.9	Load sensitivity	±10% load change (Note 3)	±0.2 max	ppm
2.10	Long term stability	Frequency drift over 1 year at 25°C	±1 max	ppm
2.11	Overall stability	For all causes including: calibration, temperature, supply voltage, load, reflow soldering and 20 years aging	±4.6 max	ppm
2.12	Holdover stability	24 hours drift at constant temperature (Telcordia GR-1244-CORE)	±40 max	ppb
3.0	POWER SUPPLY			
Line	Parameter	Test Condition	Value	Unit
3.1	Supply voltage	Nominal supply voltage 3.3V	3.14 to 3.46	V
3.2	Current	At maximum supply voltage (Note 3)	2.5 max	mA
4.0	OSCILLATOR OUTPUT -	CMOS OPTION		
Line	Parameter	Test Condition	Value	Unit
4.1	Output waveform	HCMOS		
4.2	Output voltage level low	Measured with a capacitive load of 10pF	10 max	%Vcc
4.3	Output voltage level high	Measured with a capacitive load of 10pF	90 min	%Vcc
4.4	Rise and fall times	Measured with a capacitive load of 10pF	5 max	ns
4.5	Duty cycle	Measured at 50% Vcc trigger level	45 to 55	%
4.6	Output load		10 max	pF
4.7	Settling time (frequency)	Time taken for frequency to reach specified calibration tolerance	50 max	ms

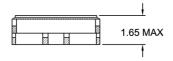
5.0	SSB PHASE NOISE			
Line	Parameter	Test Condition	Value	Unit
5.1	SSB phase noise power density at 1Hz offset	Typical value for a 12.8MHz Oscillator with 10nF external filter capacitor at 25°C. CMOS output	-70	dBc/Hz
5.2	SSB phase noise power density at 10Hz offset	Typical value for a 12.8MHz Oscillator with 10nF external filter capacitor at 25°C. CMOS output	-100	dBc/Hz
5.3	SSB phase noise power density at 100Hz offset	Typical value for a 12.8MHz Oscillator with 10nF external filter capacitor at 25°C. CMOS output	-125	dBc/Hz
5.4	SSB phase noise power density at 1kHz offset	Typical value for a 12.8MHz Oscillator with 10nF external filter capacitor at 25°C. CMOS output	-147	dBc/Hz
5.5	SSB phase noise power density at 10kHz offset	Typical value for a 12.8MHz Oscillator with 10nF external filter capacitor at 25°C. CMOS output	-152	dBc/Hz
5.6	SSB phase noise power density at 100kHz offset	Typical value for a 12.8MHz Oscillator with 10nF external filter capacitor at 25°C. CMOS output	-155	dBc/Hz
5.7	SSB phase noise power density at 1MHz offset	Typical value for a 12.8MHz Oscillator with 10nF external filter capacitor at 25°C. CMOS output	-155	dBc/Hz
6.0	ENVIRONMENTAL			
Line	Parameter	Description		
6.1	Shock	Half sine wave acceleration of 100G peak amplitude for 6ms duration 60068-2-27.	n, 3 cycles each	n plane. IEC
6.2	Humidity	After 48 hours at 85°C ± 2°C 85% relative humidity non-condensing	(Note 7).	
6.3	Thermal shock	Exposed at -40° C for 30 minutes them to 85°C for 30 minutes constant (Note 7).	antly for a perio	od of 5 days
6.4	Vibration	10G RMS from 30Hz to 1500Hz random in each of the 3 axis for 4 ho 7).	ours, total 12 h	ours (Note
6.5	Storage temperature	-40 to 85°C.		
7.0	MARKING			
Line	Parameter	Description		
7.1	Type	Engraved.		
7.2	Line 1	R and product code.		
7.3	Line 2			
		Pin 1 and date code.		
0.0	MANUIFACTURING INFO			
8.0	MANUFACTURING INFO	RMATION		
Line	Parameter	RMATION Description		
Line 8.1	Parameter Reflow	RMATION Description Solder reflow processes as per attached profile.		
Line	Parameter	RMATION Description		
8.1 8.2	Parameter Reflow Packaging description	RMATION Description Solder reflow processes as per attached profile.		
Line 8.1	Parameter Reflow	RMATION Description Solder reflow processes as per attached profile. Tape and reel. Standard packing quantity is 2000 units per reel		
8.1 8.2 9.0	Parameter Reflow Packaging description SPECIFICATION NOTES	RMATION Description Solder reflow processes as per attached profile.	held at midpoi	nt.
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9.0 Line 9.1	Parameter Reflow Packaging description SPECIFICATION NOTES Parameter Note 1	Parts should be shielded from drafts causing unexpected thermal gra	dients. Tempe	rature
9.0 Line 9.1 9.2	Parameter Reflow Packaging description SPECIFICATION NOTES Parameter Note 1 Note 2	Description Solder reflow processes as per attached profile. Tape and reel. Standard packing quantity is 2000 units per reel Description Temperature varied at maximum of 1°C per minute. Control voltage Parts should be shielded from drafts causing unexpected thermal grachanges due to ambient air currents on the oscillator can lead to should	dients. Tempe	rature
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9.0 Line 9.1 9.2 9.3 9.4	Parameter Reflow Packaging description SPECIFICATION NOTES Parameter Note 1 Note 2 Note 3 Note 4	Description Solder reflow processes as per attached profile. Tape and reel. Standard packing quantity is 2000 units per reel Description Temperature varied at maximum of 1°C per minute. Control voltage Parts should be shielded from drafts causing unexpected thermal grachanges due to ambient air currents on the oscillator can lead to sho Specified for load stated in oscillator output section. VCO of 4.5V only applicable when Vcc of 5.0V is applied.	idients. Tempe ort term frequent ired. se is required, f	rature ncy drift. requency

Drawing Name: RTX5032A Model Drawing

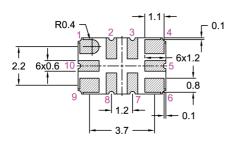
MODEL DRAWING



FRONT VIEW

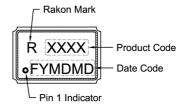


SIDE VIEW



BOTTOM VIEW

MARKING EXAMPLE





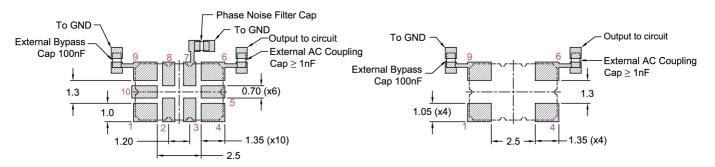
END VIEW

PIN CONNECTIONS

Without VC		With VC		
Filter Enabled	Filter Disabled	Filter Enabled	Filter Disabled	
1 NC	1 NC	1 VCO	1 VCO	
2 NC	4 GND	2 NC	4 GND	
3 NC	6 RF OUT	3 NC	6 RF OUT	
4 GND	9 VCC	4 GND	9 VCC	
5 NC		5 NC		
6 RF OUT		6 RF OUT		
7 VC FILTER		7 VC FILTER		
8 NC		8 NC		
9 VCC		9 VCC		
10 NC		10 NC		

RECOMMENDED PAD LAYOUT - FILTER ENABLED

RECOMMENDED PAD LAYOUT - FILTER DISABLED



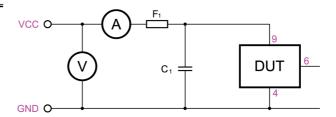
TOLERANCES: TITLE: RTX5032A MODEL FILENAME: CAT569 XX X.X REVISION: В RELATED DRAWINGS: $= \pm 0.2$ X.XX = X.XXX = $= \pm 0.13$ DATE: 22-Aug-11 SCALE: 5:1 Millimetres © 2009 Rakon Limited Hole

Drawing Name: RTX5032 Series Test Circuit

NO VOLTAGE CONTROL INPUT:

C1: 100nF.

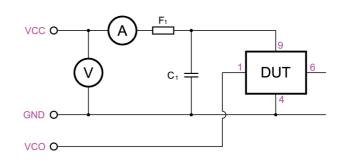
F1: A ferrite bead or a resistor between $22\Omega \sim 47\Omega$ recommended.



VOLTAGE CONTROL INPUT:

C1: 100nF.

F1: A ferrite bead or a resistor between $22\Omega \sim 47\Omega$ recommended.

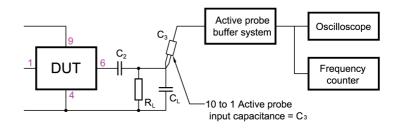


CLIPPED SINEWAVE OUTPUT:

C₂: ≥1nF

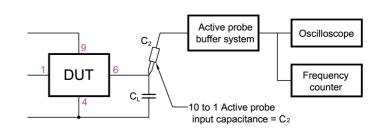
RL: 10k

CT: C_L + C₃ (C₃ - Oscilloscope probe capacitance)
CT as stated in OSCILLATOR OUTPUT section



CMOS OUTPUT:

CT: CL + C2 (C2 - Oscilloscope probe capacitance) CT as stated in OSCILLATOR OUTPUT section



TITLE: RTX5032 SERIES TEST CIRCUIT

RELATED DRAWINGS:

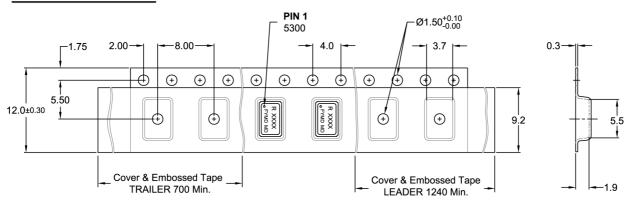
REVISION: A
DATE: 02-Dec-10
SCALE: NTS
Millimetres

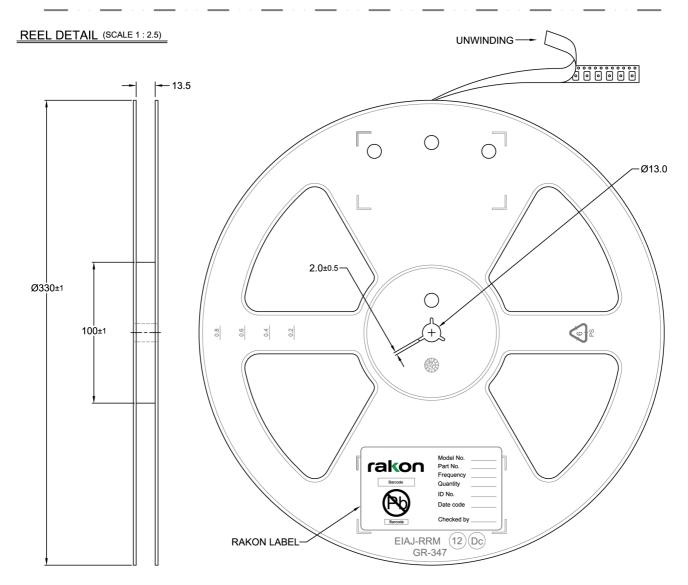


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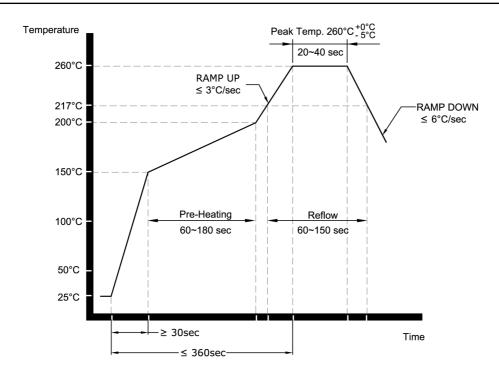
Drawing Name: I(V)T5300 Series Tape & Reel

TAPE DETAIL (SCALE 2 : 1)





Drawing Name: Pb-Free Reflow



NOTE:

The product has been tested to withstand the Reflow Profile shown. The Reflow Profile used to solder Rakon products is determined by the solder paste Manufacturer's specification. It is recommended that the Reflow Profile used does not exceed the one shown above.

TITLE: Pb-FREE REFLOW	FILENAME:	CAT541	
RELATED DRAWINGS:	REVISION:	В	
	DATE:	05-Sep-11	rakon
	SCALE:	NTS	
	Millimetres		© 2009 Rakon Limited

Specification History Current Version: 1.01

Versio n	User	Change	Note	Date
1.0	System	Specification Created		2011-10-21 10:51
1.01	andrew.daken	Changed max value in line 2.6 from '0.05' to '0.1' Changed max value in line 4.5 from '60' to '55' Changed min value in line 4.5 from '40' to '45' Changed max value in line 5.1 from '-67' to '-70' Changed max value in line 5.2 from '-97' to '-100' Changed max value in line 5.3 from '-120' to '-125' Changed max value in line 5.4 from '-141' to '-147' Changed max value in line 5.5 from '-155' to '-152'	Update frequency slope and duty cycle to match the RTX7050A version. Updated phase noise values	2012-07-19 11:56